NSN 5962-01-205-7339

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View Online at https://aerobasegroup.com/nsn/5962-01-205-7339

Body Length:	
1.290 inches	
Body Width:	
0.610 inches	
Body Height:	
0.210 inches	
Maximum Power Dissipation Rating:	
1.02 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and burn in and programmable and schottky and w/active pull-up and 3-state output	
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
14 input	
Case Outline Source And Designator:	
D-3 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
-0.5 volts power source and 7.0 volts power source	
Time Rating Per Chacteristic:	
100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level	
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).	
Terminal Type And Quantity:	
24 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

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